

# A Study on Power Stability Improvement in the Inductive Coupled RFID Transponder System

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**Abstract**—Transponders of RFID system are classified as active or passive depending on the type of power supply they use. In passive transponders the data carrier has to obtain its power from the induced voltage. The induced voltage is converted into direct current using a low loss bridge rectifier and then smoothed. In practice, the induced voltage in the transponder coil is variable according to the coupling coefficient  $k$  and the load resistance ( $R_L$ ). Therefore, the rectified voltage is unstable and the transponder of RFID is unstable sometimes. In this paper, a voltage-dependent shunt resistor ( $R_S$ ) circuits are designed and inserted in parallel with the load resistance of RFID transponder in order to improve the stability of power.

**Index Terms**—Rectifier, Transponder, Inductive Coupled Coil.

## I. INTRODUCTION

Recently, the automatic identification procedures have become very popular in many service industries, purchasing and distribution logistics, industries, manufacturing companies and material flow systems. The technically optimal solution would be the storage of data in a silicon chip. The most common form of electronic data-carrying device in use in everyday life is the smart card based upon a contact field such as traffic smart card and bank card. However, the mechanical contact used in smart card is often impractical. A contactless transfer of data between the data-carrying device and its reader is far more flexible. In the ideal case, the power required to operate the electronic data-carrying device would also be transferred from the reader using contactless technology. Because of the procedures used for the transfer of power and data, contactless ID systems are called RFID system [1, 2].

Transponders of RFID are classified as active or passive depending on the type of power supply they use. Active transponders incorporate their own battery to provide the power supply to the data carrier. In passive transponders the data carrier has to obtain its power supply from the voltage  $u_2$  induced in the transponder coil.

To achieve this, the voltage  $u_2$  is converted into direct current using a low loss bridge rectifier and then

smoothed [2].

However, in practice, the induced voltage  $u_2$  in the transponder coil very rapidly reaches high values due to resonance step-up in resonant circuit. If the coupling coefficient  $k$  is increase – possibly by reducing the gap between reader and transponder – or the load resistance  $R_L$  is increase, then voltage  $u_2$  will reach a level much greater than 100V instantly. Generally the operation of a data carrier requires a constant operating voltage of 3~5 V. The voltage  $u_2$  in the transponder coil is variable according to the coupling coefficient  $k$  and the load resistance  $R_L$ . In this paper, In order to regulate voltage  $u_2$  independently of the coupling coefficient  $k$  or other parameters, and to hold it constant in practice, we inserted a voltage-dependent shunt resistor  $R_S$  in parallel with the load resistance  $R_L$ . As induced voltage increases, the value of the shunt resistor  $R_S$  falls, thus reducing the quality of the transponder resonant circuit to such a degree that the voltage  $u_2$  remains constant.

## II. INDUCTIVE COUPLED TRANSPONDER

An inductively coupled transponder comprises an electronic data-carrying device, usually a single microchip, and a large coil that functions as an antenna. Figure 1 shows a configuration of inductive coupled reader and transponder.

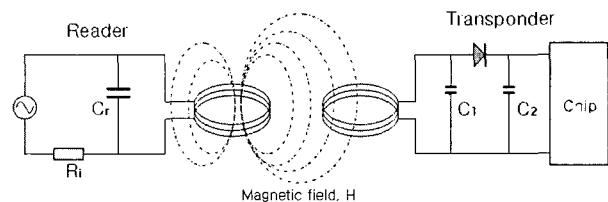


Fig. 1 Inductive Coupled Transponder

Inductively coupled transponders are almost always operated passively. This means that all the energy needed for the operation of the microchip has to be provided by reader. For this purpose, the reader's antenna coil generates a strong, high frequency electromagnetic field, which penetrates the cross-section of the coil area and the area around the coil. Because the wave length of the frequency range used is several times greater than the distance between the reader's antenna and the transponder, the electromagnetic field maybe treated as a simple magnetic alternating field to the distance between transponder and antenna [3]. A small part of the emitted field penetrates the antenna coil of the transponder,

Manuscript received April 16, 2007

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which is some distance away from the coil of the reader. A voltage  $u_2$  is generated in the transponder's antenna coil by inductance.

This voltage is rectified and serves as the power supply for the data-carrying device, microchip. As shown in figure 1, a capacitor  $C_r$  is connected in parallel with the reader's antenna's coil, the capacitance of this capacitor being selected such that it works with the coil inductance of the antenna coil to form a parallel resonant circuit with a resonant frequency that corresponds with the transmission frequency of the reader. Very high currents are generated in the antenna coil of the reader by resonance step-up in the parallel resonant circuit, which can be used to generate the required field strengths for the operation of the remote transponder [4].

The antenna coil of the transponder and the capacitor  $C_1$  form a resonant circuit tuned to the transmission frequency of the reader. The voltage at the transponder coil reaches a maximum due to resonance step-up in the parallel resonant circuit.

The layout of the two coils can also be interpreted as a transformer, in which there is only a very weak coupling between the two windings. The efficiency of power transfer between the antenna coil of the reader and the transponder is proportional to the operating frequency  $f$ , the number winding  $n$ , the area  $A$  enclosed by the transponder coil, the angle of the two coils relative to each other and the distance between the two coils.

### III. FIELD STRENGTH IN CONDUCTOR LOOPS

Conductor loops as in figure 2, short cylindrical coil, are used as magnetic antennas to generate the magnetic alternating field in the write/read devices of inductively coupled RFID systems. If the measuring point is moved away from the center of the coil along the coil axis ( $z$  axis), then the strength of the field  $H$  will decrease as the distance  $z$  is increased. The equation 1 can be used to calculate the path of field strength along the  $z$  axis of a conductor loop similar to those employed in the transmitter antennas of inductively coupled RFID systems [3].

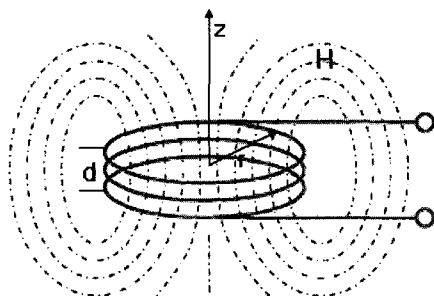


Fig. 2 Magnetic field of short cylinder coils

$$H(z) = \frac{I n r^2}{2 \sqrt{(r^2 + z^2)^3}} \quad (1)$$

In equation 1, the parameters as follows:  $n$  is the number of windings,  $r$  is the radius and  $z$  is the distance from the center of coil. Figure 3 shows the result of the magnetic field strength in relation to radius of the coil and distance along the  $z$  axis. It shows that the field strength remains constant up to a certain distance and then falls rapidly. In free space, the decay of the field strength is approximately 60dB/decade in the near field of the coil, and flattens out to 20dB/decade in the far field of the electromagnetic wave that generated.

Figure 4 shows the graph of field strength  $H$  as the coil radius  $r$  is varied. The optimal coil radius for different read ranges is always the maximum point of graph  $H(r)$ . The relationship between the maximum field strength  $H$  and the coil radius  $r$  could be found from equation 1. The first derivative  $H'(r)$  is driven by differentiating  $H(r)$  with respect to  $r$  as following:

$$H'(r) = \frac{d}{dr} H(r) = \frac{2 I n r}{\sqrt{(r^2 + z^2)^3}} - \frac{3 I n r^3}{(r^2 + z^2)\sqrt{(r^2 + z^2)^3}} \quad (2)$$

The inflection point, and thus the maximum value of the function  $H(r)$ , is found from the following zero point of the derivative  $H'(r)$ . The relationship between the maximum field strength  $H$  and the coil radius  $r$  could be found as equation 3.

$$r = \sqrt{2} z \quad (3)$$

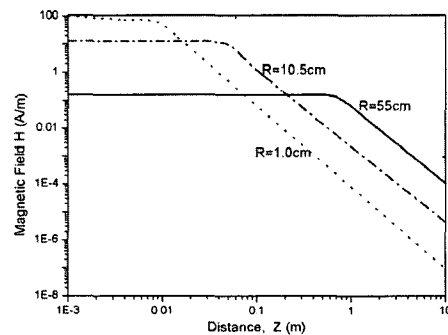


Fig. 3 Magnetic field strength  $H$  in the near field of short cylinder coils

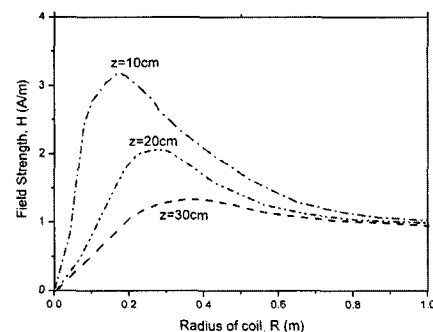


Fig. 4 Field strength  $H$  of a transmission antenna given distance  $z$  and variable  $r$ . ( $I=1A$ ,  $n=1$ )

#### IV. INDUCED VOLTAGE AND RESONANCE

Any change to the magnetic flux generates the electric field strength. This characteristic of the magnetic field is described by Faraday's law. In general form Faraday's law is written as follows:

$$u_i = \oint E_i \cdot ds = - \frac{d\Psi(t)}{dt} \quad (4)$$

Figure 5 shows the equivalent circuit diagram for coupled conductor loops. In an inductively coupled RFID system  $L_1$  would be the transmitter antenna of the reader.  $L_2$  represents the antenna of the transponder, where  $R_2$  is the coil resistance of the transponder antenna. The current consumption of the data memory is symbolized by the load resistor  $R_L$ .

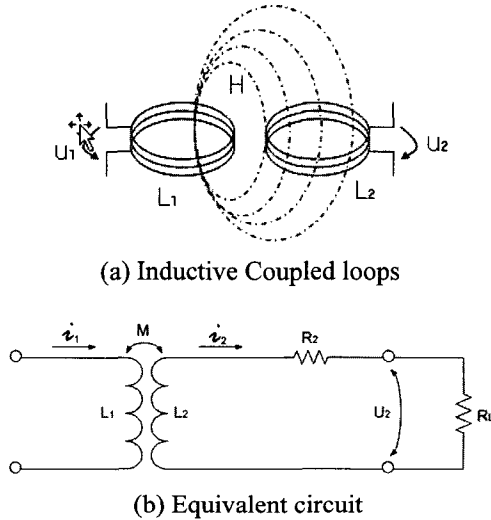


Fig. 5 Coupled loops and its equivalent circuit

A time varying flux in the conductor loop  $L_1$  induces voltage  $u_2$  in the conductor loop  $L_2$  due to mutual inductance  $M$ . The flow of current creates an additional voltage drop across the coil resistance  $R_2$ , meaning that the voltage  $u_2$  can be measured at the terminals. Therefore, we can get the equation for load voltage  $u_2$  as follows [5]:

$$u_2 = \frac{d\Psi_2}{dt} = M \frac{di_1}{dt} - L_2 \frac{di_2}{dt} - i_2 R_2 \quad (5)$$

$$u_2 = j\omega M \cdot i_1 - j\omega L_2 \cdot i_2 - i_2 R_2 \quad (6)$$

$$u_2 = \frac{j\omega M \cdot i_1}{1 + \frac{j\omega L_2 + R_2}{R_L}} \quad (7)$$

The voltage  $u_2$  induced in the transponder coil is used to provide the power supply to the microchip. In order to improve the efficiency of the equivalent circuit in Figure 5, an additional capacitor  $C_2$  is connected in parallel with

the coil  $L_2$  to form a resonant circuit with a resonant frequency that corresponds with the operating frequency if the RFID system [6, 7].

In practice,  $C_2$  is made up of a parallel capacitor  $C'_2$  and a parasitic capacitance  $C_p$  from the real circuit.  $C_2 = (C'_2 + C_p)$ . The required capacitance for the parallel capacitor  $C'_2$  is as follows, taking into account the parasitic capacitance  $C_p$  [8, 9]:

$$C'_2 = \frac{1}{(2\pi f)^2 L_2} - C_p \quad (8)$$

Figure 6 shows the equivalent of a real transponder.  $R_2$  is the natural resistance of the transponder coil  $L_2$ , the current consumption of the microchip is represented by  $R_L$  and  $u_s$  is induced voltage in coil  $L_2$ . The  $u_p$  is the voltage at the data carrier load resistor  $R_L$  in Figure 6, can be represented as follows [3]:

$$u_2 = \frac{u_s}{1 + (j\omega L_2 + R_2)(1/R_L + j\omega C_2)} \quad (9)$$

$$= \frac{\omega k \sqrt{L_1 L_2} i_1}{\sqrt{(\omega L_2 / R_L + \omega R_2 C_2)^2 + (1 - \omega^2 L_2 C_2 + R_2 / R_L)^2}}$$

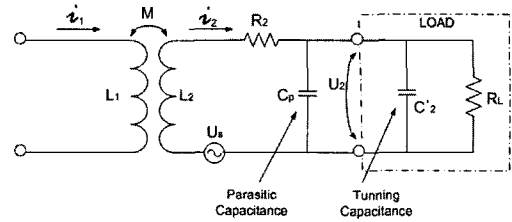


Fig. 6 Equivalent circuit of inductively coupled loops with resonant capacitor.

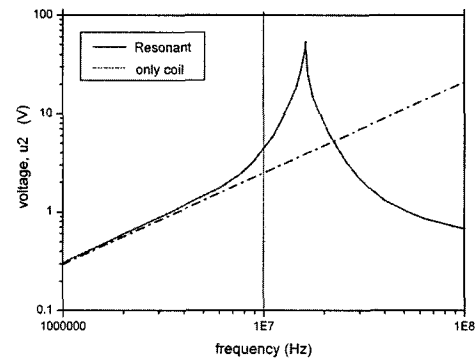


Fig. 7 Resonance characteristics of voltage  $u_p$ .

Figure 7 compares voltage  $u_2$  for the circuit with the coil alone shown in Figure 5 and for the circuit with resonance of Figure 6. The graph is almost identical at frequencies below the resonant frequencies of both circuits, but when the resonant is reached, voltage increases by more than a power of ten in the parallel resonant circuit compared to the voltage for coil alone. However, above the resonant frequency voltage  $u_2$  falls rapidly in the resonant circuit, even falling below the value for the coil alone.

### V. VOLTAGE REGULATION AND RESULTS

In the circuit as figure 6, the induced voltage  $u_2$  in the transponder coil very rapidly reaches high values due to resonance step-up in resonant circuit. If the coupling coefficient  $k$  is increase – possibly by reducing the gap between reader and transponder – or the load resistance  $R_L$  is increase, then voltage  $u_2$  will reach a level much greater than 100V. Generally the operation of a data carrier requires a constant operating voltage of 3~5 V. The voltage  $u_2$  in the transponder coil is variable according to the coupling coefficient  $k$  and the load resistance  $R_L$ . In this paper, In order to regulate voltage  $u_2$  independently of the coupling coefficient  $k$  or other parameters, and to hold it constant in practice, a voltage-dependent shunt resistor ( $R_S$ ) regulator is inserted in parallel with the load resistance as shown in Figure 8.

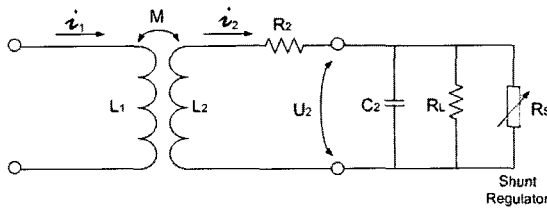


Fig. 8 Voltage regulation in the transponder using a shunt regulator.

As induced voltage increases, the value of the shunt resistor  $R_S$  falls, thus reducing the quality of the transponder resonant circuit to such a degree that the voltage  $u_2$  remains constant.

In equation 9, to calculator the value of the shunt resistor for different variables, replace  $R_L/R_S$  into the constant  $R_L$ . The equation can be solved with respect to  $R_S$ . The variable voltage  $u_2$  is replaced by the constant voltage  $u_{REG}$  – the desired input voltage of the data carrier – giving the following equation for  $R_S$ :

$$R_S = \left| \frac{1}{t_U / (j\omega L_2 + R_2) - j\omega C_2 - 1/R_L} \right| \quad (10)$$

where,

$$t_U = \left( \frac{j\omega k \sqrt{L_1 L_2} i_1}{u_{REG}} \right) - 1 \quad | u_{2-unreg} > u_{REG}$$

Figure 9 shows the simulation graph of voltage  $u_2$  when such an ideal shunt regulator is used. Voltage  $u_2$  initially increases in proportion with the coupling coefficient  $k$ . When  $u_2$  reaches its desired value, the value of shunt resistor begins to fall in inverse proportion to  $k$ , thus maintaining an almost constant value for voltage  $u_2$ . This simulation is based on the following parameters:  $i_1 = 0.5A$ ,  $L_1 = 1\mu H$ ,  $L_2 = 3.5\mu H$ ,  $R_L = 2k\Omega$ ,  $C_2 = 1/\omega_2 L_2$

Figure 10 shows the variable value of shunt resistor  $R_S$  as a function of the coupling coefficient. This can only achieved using a semiconductor circuit. In this paper, we

designed the circuit for the shunt resistor  $R_S$  as represented in Figure 11. It is configured with the Zener diode, transistor and resistors. The characteristic of the shunt resistor  $R_S$  for coupling coefficient is shown in figure 10. The characteristic results of regulator with and without shunt resistor  $R_S$  are shown in figure 12.

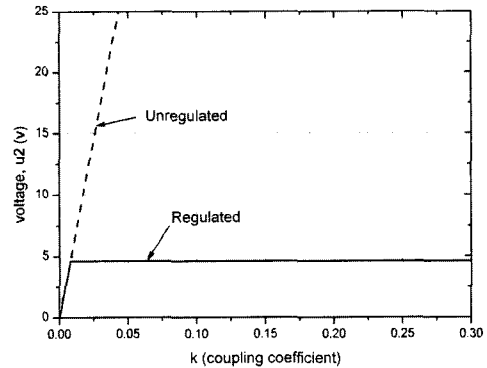


Fig. 9 The graph of voltage  $u_2$  with and without shunt regulation in transponder.

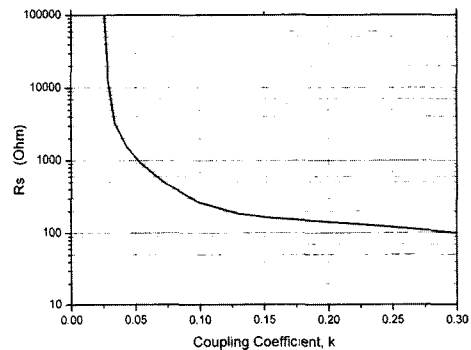


Fig. 10 The shunt resistor  $R_S$  as a function of the coupling coefficient  $k$ .

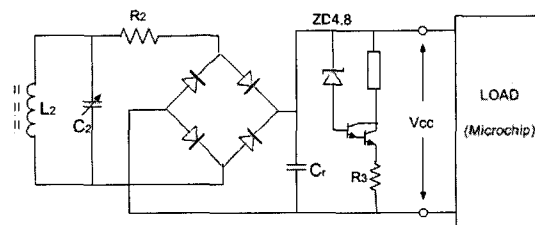


Fig. 11 The designed circuit for a shunt regulator.

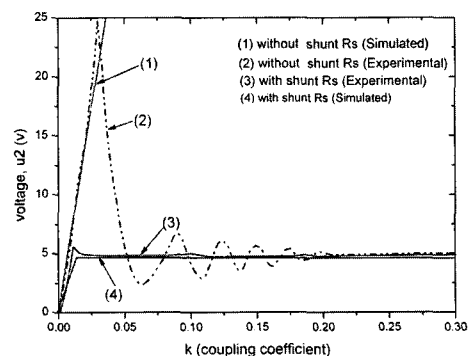


Fig: 12 The characteristics of regulator with and without shunt resistor  $R_S$

## VI. CONCLUSIONS

In passive transponders the data carrier has to obtain its power supply from the voltage  $u_2$  induced in the transponder coil. The voltage  $u_2$  is converted into direct current using a low loss bridge rectifier and then smoothed. In practice, the induced voltage  $u_2$  in the transponder coil very rapidly reaches high values due to resonance step-up in resonant circuit. The voltage  $u_2$  in the transponder coil is variable according to the coupling coefficient  $k$  and the load resistance  $R_L$ . In this paper, in order to regulate voltage  $u_2$  independently of the coupling coefficient  $k$  or other parameters, and to hold it constant in practice, we designed and inserted a voltage-dependent shunt resistor ( $R_S$ ) circuit in parallel with the load resistance  $R_L$ . As induced voltage increases, the value of the shunt resistor  $R_S$  falls, thus reducing the quality of the transponder resonant circuit to such a degree that the voltage  $u_2$  remains constant as shown in figure 12.

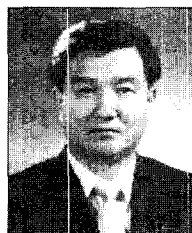
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